NSN 5962-01-484-1008

Memory Microcircuit - Page 1 of 1



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End Application:
Joint stars
Features Provided:
Electrostatic sensitive
Criticality Code Justification:
Cbbl
Product Name:
Digital interface m
Voltage Rating And Type Per Characteristic:
3.3 volts power source
Memory Device Type:
Ram
Hybrid Technology Type:
Monolithic
Special Features:
128mb sdram dimm 100mhz cl2 single density
Terminal Type And Quantity:
200 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0